

Features

- · Split Gate Trench MOSFET Technology
- · Low Thermal Resistance
- · Moisture Senstivity Level 3
- Halogen Free. "Green" Device (Note 1)
- Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

Maximum Ratings

Operating Junction Temperature Range : -55°C to +150°C

Storage Temperature Range: -55°C to +150°C

• Thermal Resistance: 40°C/W Junction to Ambient(Note 2)

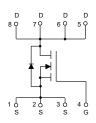
Thermal Resistance: 1.16°C/W Junction to Case

Parameter		Symbol	Rating	Unit	
Drain-Source Voltage		V _{DS}	100	V	
Gate-Source Volltage		V _{GS}	±20	V	
Continuous Drain Current	T _C =25°C	- I _D	120	А	
	T _C =100°C		75		
Pulsed Drain Current ^(Note 3)		I _{DM}	480	Α	
Total Power Dissipation(Note 4)		P _D	108	W	
Single Pulsed Avalanche Energy ^(Note 5)		E _{AS}	552	mJ	

Note:

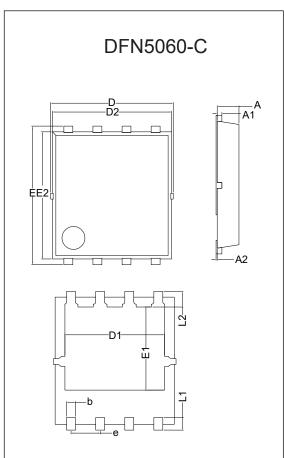
- 1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 2. The value of RθJA is measured with the device mounted on 1 in ² FR-4 board with 2oz. copper, in a still air environment with TJ=25°C.
- 3. Repetitive rating; pulse width limited by max. junction temperature.
- 4. PD is based on max. junction temperature, using junction-case thermal resistance.
- 5. V_{DD} =50V, R_{G} =25 Ω , V_{G} =10V,L=2mH.

Internal Structure and Marking Code





N-CHANNEL MOSFET



	DIMENSIONS					
DIM	INCHES		MM		NOTE	
	MIN	MAX	MIN	MAX	NOTE	
D	0.203	0.218	5.15	5.55		
D2	0.201	0.209	5.10	5.30		
E	0.234	0.242	5.95	6.15		
E2	0.215	0.222	5.45	5.65		
Α	0.033	0.041	0.85	1.05		
A1	0.008		0.203		BSC	
A2	0.000	0.004	0.00	0.10		
D1	0.167	0.175	4.25	4.45		
E1	0.139	0.147	3.52	3.73		
L1	0.018	0.026	0.45	0.65		
L2	0.027		0.68		BSC	
b	0.012	0.020	0.30	0.50		
е	0.050		1.27		BSC	

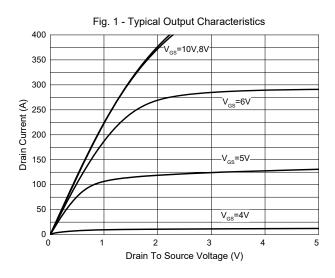


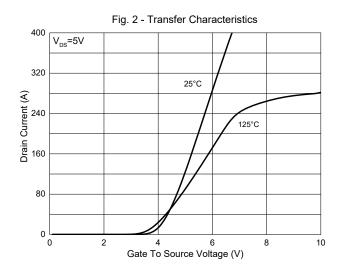
Electrical Characteristics @ 25°C (Unless Otherwise Specified)

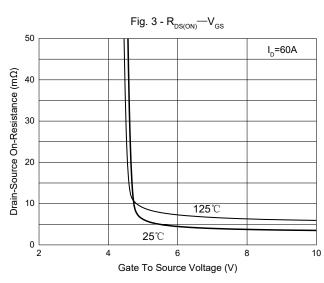
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static Characteristics				1	1		
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} =0V, I _D =250μA	100			V	
Gate-Source Leakage Current	I _{GSS}	V _{DS} =0V, V _{GS} =±20V			±100	nA	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =100V, V _{GS} =0V			1	μΑ	
Gate-Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=250\mu A$	2.0	2.8	4.0	V	
Drain-Source On-Resistance		V _{GS} =10V, I _D =60A		3.5	4.2	4.2 mΩ	
	R _{DS(on)}	V _{GS} =10V, I _D =20A	3.5 4.2		4.2	11122	
Diode Characteristics			,		1		
Continuous Body Diode Current	Is				120	А	
Diode Forward Voltage	V _{SD}	V _{GS} =0V, I _S =60A		0.9	1.2	V	
Reverse Recovery Time	t _{rr}	- I _F =60A, dI _F /dt=100A/μs		52		ns	
Reverse Recovery Charge	Q _{rr}	- 1 _F -00Λ, α1 _F /ατ-100Λ/μ5		58		nC	
Dynamic Characteristics			·				
Input Capacitance	C _{iss}			4551			
Output Capacitance	C _{oss}	V _{DS} =50V,V _{GS} =0V,f=1MHz		1648		pF	
Reverse Transfer Capacitance	C _{rss}			27		1	
Total Gate Charge	Qg			66			
Gate-Source Charge	Q_{gs}	V _{DS} =50V,V _{GS} =10V,I _D =60A		27		nC	
Gate-Drain Charge	Q_{gd}			8.6			
Turn-On Delay Time	t _{d(on)}			24			
Turn-On Rise Time	t _r	V _{DS} =50V, V _{GEN} =10V,		50		,	
Turn-Off Delay Time	t _{d(off)}	$R_G=3\Omega$, $I_{DS}=60A$		44		ns	
Turn-Off Fall Time	t _f			15			

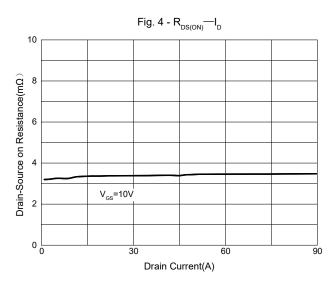


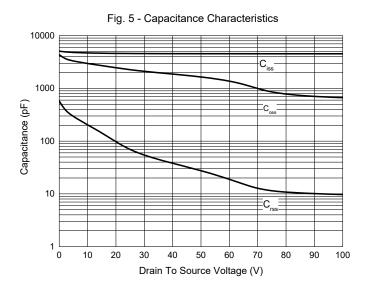
Curve Characteristics

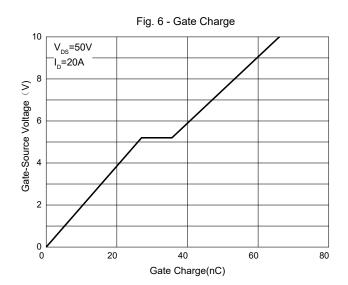






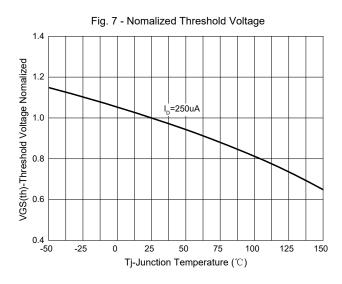


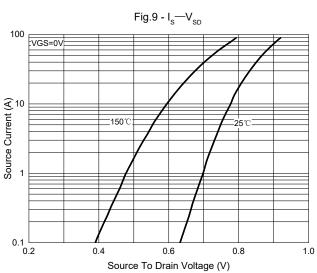


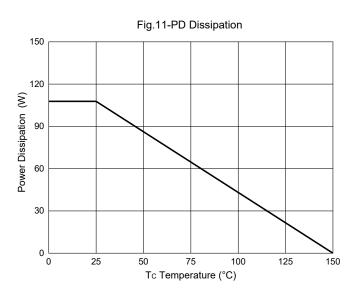


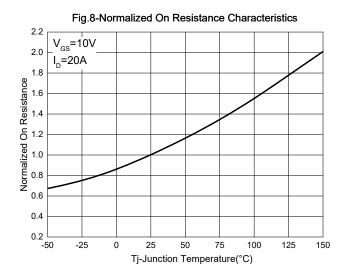


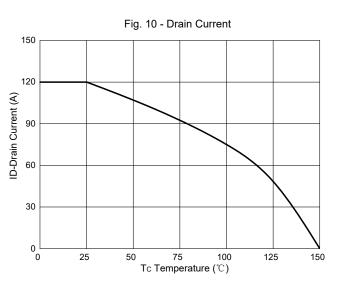
Curve Characteristics





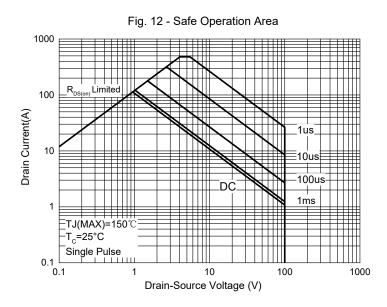








Curve Characteristics



10 D=Ton/T In descending order D=0.5,0.3, 0.2, 0.1, 0.05, 0.02, 0.01, single pulse TJ,PK=Tc+Pdm·Zθjc·Rθjc Zth(J-C) Normalized Transient RθjC=1.16°C/W Thermal Resistance Single Pulse P_{DM} 1E-3 1E-6 1E-5 1E-4 1E-3 0.01 0.1 Pulse Width (s)

Fig. 13 -Normalized Transient Thermal Impedance



Ordering Information

Device	Packing
Part Number-TP	Tape&Reel: 5Kpcs/Reel

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